

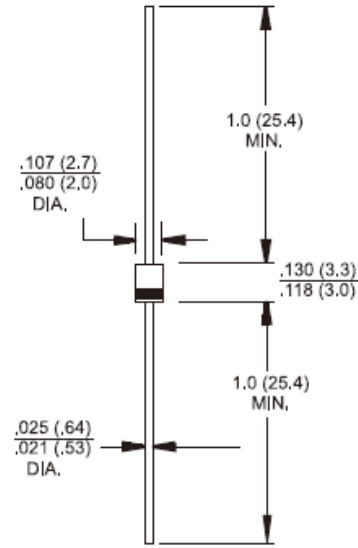
**TS-1**

**Features**

- ✧ High efficiency, low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss
- ✧ For use in low voltage, high frequency inverter, Free wheeling, and polarity protection application
- ✧ Green compound with suffix "G" on packing code & prefix "G" on datecode

**Mechanical Data**

- ✧ Case: Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Lead: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode
- ✧ High temperature soldering guaranteed: 260 °C/10 seconds/.375", (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ✧ Mounting position: Any
- ✧ Weight: 0.20 grams



**Dimensions in inches and (millimeters)**

**Marking Diagram**



- SFT1XG = Specific Device Code
- G = Green Compound
- Y = Year
- M = Work Month

**Maximum Ratings and Electrical Characteristics**

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	SFT 11G	SFT 12G	SFT 13G	SFT 14G	SFT 15G	SFT 16G	SFT 17G	SFT 18G	Units	
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	500	600	V	
Maximum RMS Voltage	$V_{RMS}$	35	70	105	140	210	280	350	420	V	
Maximum DC Blocking Voltage	$V_{DC}$	50	100	150	200	300	400	500	600	V	
Maximum Average Forward Rectified Current	$I_{F(AV)}$	1								A	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	30								A	
Maximum Instantaneous Forward Voltage (Note 1) @ 1 A	$V_F$	0.95			1.3		1.7			V	
Maximum DC Reverse Current at Rated DC Blocking Voltage @ $T_A=25\text{ }^\circ\text{C}$	$I_R$	5								uA	
@ $T_A=125\text{ }^\circ\text{C}$		100									
Maximum Reverse Recovery Time (Note 2)	$T_{rr}$	35									nS
Typical Junction Capacitance (Note 3)	$C_j$	20				10					pF
Typical Thermal Resistance	$R_{\theta JA}$	100								$^\circ\text{C/W}$	
Operating Temperature Range	$T_J$	- 65 to + 150								$^\circ\text{C}$	
Storage Temperature Range	$T_{STG}$	- 65 to + 150								$^\circ\text{C}$	

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle

Note 2: Reverse Recovery Test Conditions:  $I_F=0.5A$ ,  $I_R=1.0A$ ,  $I_{RR}=0.25A$

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

## RATINGS AND CHARACTERISTIC CURVES (SFT11G THRU SFT18G)

FIG. 1- MAXIMUM AVERAGE FORWARD CURRENT DERATING

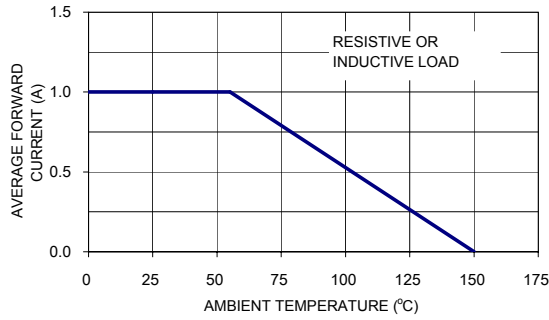


FIG. 2- TYPICAL REVERSE CHARACTERISTICS

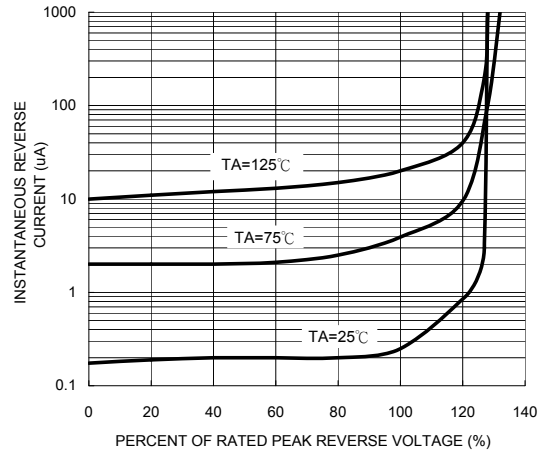


FIG. 3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

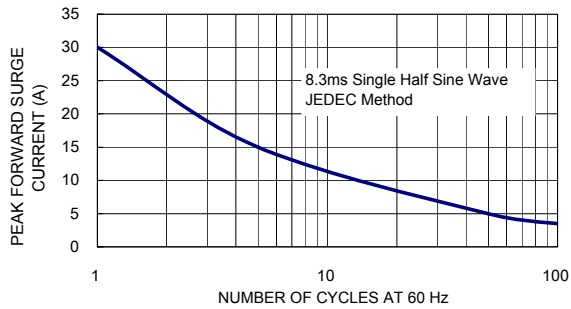


FIG. 5- TYPICAL FORWARD CHARACTERISTICS

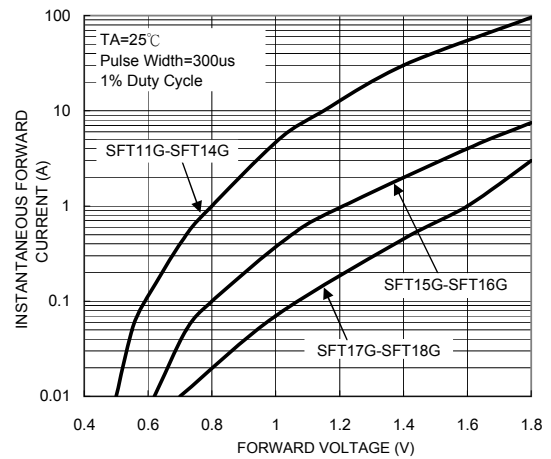


FIG. 4- TYPICAL JUNCTION CAPACITANCE

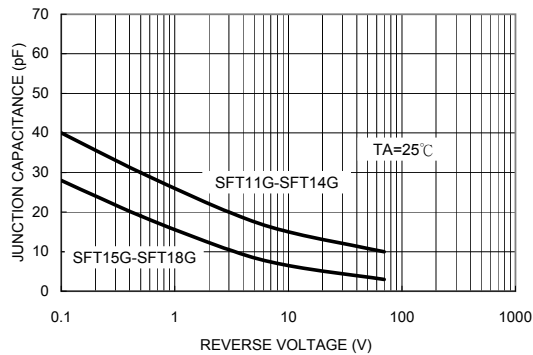


FIG. 6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

